# 2SD2136

## Silicon NPN triple diffusion planar type

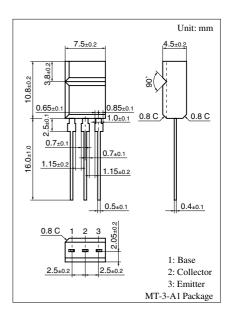
For power amplification Complementary to 2SB1416

#### ■ Features

- $\bullet$  High forward current transfer ratio  $h_{\text{FE}}$  which has satisfactory linearity
- ullet Low collector to emitter saturation voltage  $V_{\text{CE(sat)}}$
- Allowing supply with the radial taping

### ■ Absolute Maximum Ratings $T_C = 25$ °C

| Parameter                    | Symbol           | Rating      | Unit |
|------------------------------|------------------|-------------|------|
| Collector to base voltage    | V <sub>CBO</sub> | 60          | V    |
| Collector to emitter voltage | V <sub>CEO</sub> | 60          | V    |
| Emitter to base voltage      | V <sub>EBO</sub> | 6           | V    |
| Peak collector current       | I <sub>CP</sub>  | 5           | A    |
| Collector current            | $I_{C}$          | 3           | A    |
| Collector power dissipation  | $P_{C}$          | 1.5         | W    |
| Junction temperature         | T <sub>j</sub>   | 150         | °C   |
| Storage temperature          | $T_{stg}$        | -55 to +150 | °C   |



### ■ Electrical Characteristics $T_C = 25$ °C

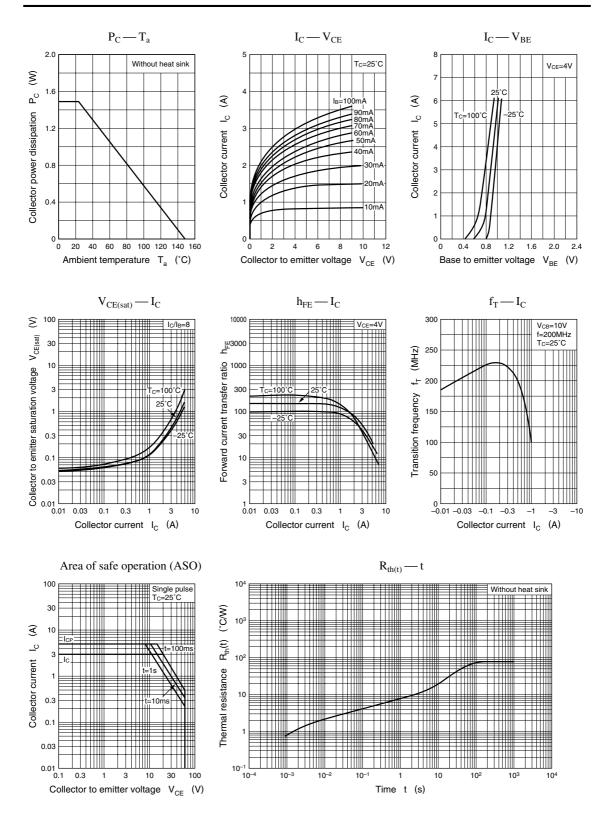
| Parameter                               | Symbol               | Conditions   | Min | Тур | Max | Unit |
|---|----------------------|--|-----|-----|-----|------|
| Collector cutoff current                | I <sub>CES</sub>     | $V_{CE} = 60 \text{ V}, V_{BE} = 0$                                  |     |     | 200 | μΑ   |
|   | $I_{CEO}$            | $V_{CE} = 60 \text{ V}, I_{B} = 0$                                   |     |     | 300 | μA   |
| Emitter cutoff current                  | $I_{EBO}$            | $V_{EB} = 6 \text{ V}, I_{C} = 0$                                    |     |     | 1   | mA   |
| Collector to emitter voltage            | V <sub>CEO</sub>     | $I_C = 30 \text{ mA}, I_B = 0$                                       | 60  |     |     | V    |
| Forward current transfer ratio          | h <sub>FE1</sub> *   | $V_{CE} = 4 \text{ V}, I_{C} = 1 \text{ A}$                          | 40  |     | 250 |      |
|   | h <sub>FE2</sub>     | $V_{CE} = 4 \text{ V}, I_{C} = 3 \text{ A}$                          | 10  |     |     |      |
| Base to emitter voltage                 | $V_{BE}$             | $V_{CE} = 4 \text{ V}, I_{C} = 3 \text{ A}$                          |     |     | 1.8 | V    |
| Collector to emitter saturation voltage | V <sub>CE(sat)</sub> | $I_C = 3 \text{ A}, I_B = 0.375 \text{ A}$                           |     |     | 1.2 | V    |
| Transition frequency                    | $f_T$                | $V_{CE} = 5 \text{ V}, I_{E} = -0.1 \text{ A}, f = 200 \text{ MHz}$  |     | 220 |     | MHz  |
| Turn-on time                            | t <sub>on</sub>      | $I_C = 1 \text{ A}, I_{B1} = 0.1 \text{ A}, I_{B2} = -0.1 \text{ A}$ |     | 0.5 |     | μs   |
| Storage time                            | t <sub>stg</sub>     |  |     | 2.5 |     | μs   |
| Fall time                               | t <sub>f</sub>       |  |     | 0.4 |     | μs   |

Note) \*: Rank classification

| Rank             | Р        | Q         | R          |  |
|------------------|----------|-----------|------------|--|
| h <sub>FE1</sub> | 40 to 90 | 70 to 150 | 120 to 250 |  |

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